## <sup>207</sup>**Pb(p,p'**γ) **IAR 1981Di08**

History				
Туре	Author	Citation	Literature Cutoff Date	
Full Evaluation	F. G. Kondev, S. Lalkovski	NDS 112, 707 (2011)	1-Aug-2010	

**1981Di08**: Facility: Univ. of Washington Tandem; Beam: 16.2-17.8 MeV; Target: rotating, 0.5-1 mg/cm<sup>2</sup> enriched in <sup>207</sup>Pb; Detectors: Si(Li), Na(I) with active anti-Compton shield; Measured: E(p), I(p), pγ-coin., FWHM=35 keV for protons.

## <sup>207</sup>Pb Levels

E(level) <sup>†</sup>	$J^{\pi \#}$	Comments	
0	1/2-		
570 <sup>‡</sup>	5/2-		
898 <sup>‡</sup>	3/2-		
4100 <sup>‡</sup>	3/2-		
4140 <sup>‡</sup>	$(5/2)^{-}$		
4390	5/2+	$J^{\pi}$ : Strongly enhanced on d5/2 analog resonance. $\gamma$ branching: decays mainly to the 898 keV level, but level seen in p- $\gamma$ coincidence with a $\gamma$ to the ground state.	
4630	1/2+	J <sup><math>\pi</math></sup> : Strongly enhanced on s1/2 analog resonance. $\gamma$ branching: I $\gamma$ (g.s.):I $\gamma$ (570):I $\gamma$ (898)=86% 9: $\leq$ 3% 6:11% 4. From the adopted J <sup><math>\pi</math></sup> values, the transition to the 570 keV level is expected to be M2.	
4870			
4980	2/2+		
5220	3/2	J <sup>**</sup> : Strongly enhanced on d <sub>5</sub> /2 analog resonance.	
5600			
5700			
5900	(1/0+ 2/0+)	Strongly enhanced on $d3/2$ resonance, but probably contains many levels.	
6150	$(1/2^+, 3/2^+)$	$J^{*}$ : Enhanced on $s_{1/2}$ resonance. Probable configuration $((N_{4s_{1/2}})(N_{3p_{3/2}}, -1)(N_{3p_{1/2}}, -1))$ .	

<sup>†</sup> From 1981Di08, unless otherwise noted. Above 6150 keV, no clearly defined peaks are seen, but a very broad distribution of d3/2 strength extends between roughly 6500 keV and 7000 keV.

<sup>‡</sup> Rounded-off value from Adopted Levels. The 4103 keV and 4140 keV levels were only partially resolved.

<sup>#</sup> From Adopted Levels. Jp arguments based on data from this experiment are given in comments.